

isc Silicon NPN RF Transistor

DESCRIPTION

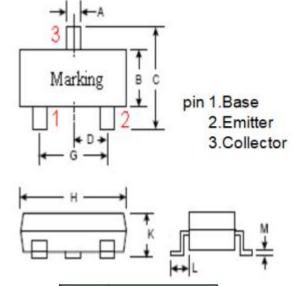
- High gain bandwidth product
 fT = 8 GHz (Typ) @ VcE=6V,Ic=30mA,f=1GHz
- High gain, low noise figure $\mid S_{21e} \mid {}^2=12 dB \quad @ \text{V}_{\text{CE}}=6\text{V}, \text{I}_{\text{C}}=30\text{mA}, \text{f}=1\text{GHz}$ $NF=2 dB (\text{Typ} \) \quad @ \text{V}_{\text{CE}}=6\text{V}, \text{I}_{\text{C}}=5\text{mA}, \text{f}=1\text{GHz}$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• UHF / VHF wide band amplifier

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	20	V	
V _{CEO}	Collector-Emitter Voltage	10	V	
V _{EBO}	Emitter-Base voltage	1.5	V	
Ic	Collector Current-Continuous	50	mA	
Pc	Collector Power Dissipation @ T _C =25℃	wer Dissipation 360		
Тл	Junction Temperature	150	$^{\circ}\!\mathbb{C}$	
T _{stg}	Storage Temperature Range	-65~150	°C	



	SOT-23			
符号	最小值 (mm)	最大值 (mm)		
Α	0.3	0.5		
В	1.2	1.4		
С	2.25	2.55		
D	0.95			
G	1.8	2		
Н	2.8	3		
K	0.9	1.15		
L	0.55			
М	0.08	0.15		

isc website: www.iscsemi.com

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PBR941

ELECTRICAL CHARACTERISTICS

 T_c =25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CBO}	Collector-Base Breakdown Voltage	Ic= 1uA ; I _E = 0	20			V
I _{CBO}	Collector Cutoff Current	V _{CB} = 10V ; I _E = 0			0.1	uA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 1V; I _C = 0			0.1	uA
h _{FE-1}	DC Current Gain	Ic= 5mA ; Vc== 6V	50		200	
h _{FE-2}	DC Current Gain	Ic= 15mA ; Vc== 6V		100		
C _{re}	Feedback Capacitance	V _{CB} =10V,I _E =0mA,f=1MHz		0.65		pF
f⊤	Current-Gain—Bandwidth Product	V _{CE} =6V,I _C =30mA,f=1GHz		8		GHz
S _{21e} ²	Power gain	V _{CE} =6V,I _C =30mA,f=1GHz		12		dB
NF	Noise figure	V _{CE} =6V,I _C =5mA,f=1GHz		2		dB

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